

Search History

L Number	Hits	Search Text	DB	Time stamp
1	1520882	memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:02
2	2179771	resistive or resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:02
3	107461	sens\$4 near2 circuit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:03
4	65919	charg\$4 near2 circuit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:03
5	41447	discharg\$4 near2 circuit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:03
6	586157	capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:04
7	10743	capacitor near2 reference	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:04
8	139073	memory and (resistive or resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:05
9	14237	(memory and (resistive or resistance)) and (sens\$4 near2 circuit)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:05
10	2171	((memory and (resistive or resistance)) and (sens\$4 near2 circuit)) and (charg\$4 near2 circuit)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:05
11	481	((memory and (resistive or resistance)) and (sens\$4 near2 circuit)) and (charg\$4 near2 circuit)) and (discharg\$4 near2 circuit)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:05
12	390	((memory and (resistive or resistance)) and (sens\$4 near2 circuit)) and (charg\$4 near2 circuit)) and (discharg\$4 near2 circuit)) and capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:05
13	58	((memory and (resistive or resistance)) and (sens\$4 near2 circuit)) and (charg\$4 near2 circuit)) and (discharg\$4 near2 circuit)) and capacitor) and (capacitor near2 reference)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/31 16:05